Preferred Device

General Purpose Transistor

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SOT-323/SC-70 package which is designed for low power surface mount applications.

Features

• Pb-Free Package is Available

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Collector – Emitter Voltage	V _{CEO}	40	Vdc
Collector - Base Voltage	V _{CBO}	75	Vdc
Emitter – Base Voltage	V _{EBO}	6.0	Vdc
Collector Current – Continuous	Ic	600	mAdc

THERMAL CHARACTERISTICS

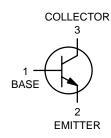
Characteristic	Symbol	Max	Unit
Total Device Dissipation FR-5 Board T _A = 25°C	P _D	150	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	833	°C/W
Junction and Storage Temperature	T _J , T _{stg}	-55 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.



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SC-70 CASE 419 STYLE 3

MARKING DIAGRAM



P1 = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location)
*Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

Device	Shipping [†]	
MMBT2222AWT1	SC-70	3000/Tape & Reel
MMBT2222AWT1G	SC-70 (Pb-Free)	3000/Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Preferred devices are recommended choices for future use and best overall value.

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Charac	cteristic	Symbol	Min	Max	Unit	
OFF CHARACTERISTICS						
Collector – Emitter Breakdown Voltage (Note $(I_C = 1.0 \text{ mAdc}, I_B = 0)$: 1)	V _{(BR)CEO}	40	_	Vdc	
Collector – Base Breakdown Voltage (I _C = 10 μAdc, I _E = 0)		V _{(BR)CBO}	75	_	Vdc	
Emitter – Base Breakdown Voltage ($I_E = 10 \mu Adc, I_C = 0$)		V _{(BR)EBO}	6.0	_	Vdc	
Base Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc)		I _{BL}	-	20	nAdc	
Collector Cutoff Current (V _{CE} = 60 Vdc, V _{EB} = 3.0 Vdc)		I _{CEX}	-	10	nAdc	
ON CHARACTERISTICS (Note 1)		-		•		
DC Current Gain (Note 1) $ \begin{aligned} &(I_C = 0.1 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 1.0 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 10 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 150 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \\ &(I_C = 500 \text{ mAdc, } V_{CE} = 10 \text{ Vdc}) \end{aligned} $		H _{FE}	35 50 75 100 40	- - - 300 -	-	
Collector – Emitter Saturation Voltage (Note 1) (I _C = 150 mAdc, I _B = 15 mAdc) (I _C = 500 mAdc, I _B = 50 mAdc)		V _{CE(sat)}	_ _	0.3 1.0	Vdc	
$\begin{aligned} \text{Base-Emitter Saturation Voltage (Note 1)} \\ \text{(I}_{\text{C}} &= 150 \text{ mAdc, I}_{\text{B}} = 15 \text{ mAdc)} \\ \text{(I}_{\text{C}} &= 500 \text{ mAdc, I}_{\text{B}} = 50 \text{ mAdc)} \end{aligned}$		V _{BE(sat)}	0.6	1.2 2.0	Vdc	
SMALL-SIGNAL CHARACTERISTICS						
Current-Gain - Bandwidth Product (I _C = 20 mAdc, V _{CE} = 20 Vdc, f = 100 M	Hz)	f _T	300	_	MHz	
Output Capacitance ($V_{CB} = 10 \text{ Vdc}$, $I_E = 0$, $f = 1.0 \text{ MHz}$)		C _{obo}	_	8.0	pF	
Input Capacitance ($V_{EB} = 0.5 \text{ Vdc}$, $I_{C} = 0$, $f = 1.0 \text{ MHz}$)		C _{ibo}	_	30	pF	
Input Impedance ($V_{CE} = 10 \text{ Vdc}$, $I_{C} = 10 \text{ mAdc}$, $f = 1.0 \text{ kH}$	h _{ie}	0.25	1.25	kΩ		
Voltage Feedback Ratio (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kH	h _{re}	_	4.0	X 10 ⁻⁴		
Small – Signal Current Gain (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kH	h _{fe}	75	375	_		
Output Admittance (V _{CE} = 10 Vdc, I _C = 10 mAdc, f = 1.0 kH	h _{oe}	25	200	μmhos		
Noise Figure ($V_{CE} = 10 \text{ Vdc}, I_{C} = 100 \mu\text{Adc}, R_{S} = 1.0$	NF	-	4.0	dB		
SWITCHING CHARACTERISTICS						
Delay Time	$(V_{CC} = 3.0 \text{ Vdc}, V_{BE} = -0.5 \text{ Vdc},$	t _d	_	10	no	
Rise Time	I _C = 150 mAdc, I _{B1} = 15 mAdc)	t _r	_	25	ns	
Storage Time	(V _{CC} = 30 Vdc, I _C = 150 mAdc,	t _s	-	225	- ns	
Fall Time	$I_{B1} = I_{B2} = 15 \text{ mAdc}$	t _f	-	60	113	

^{1.} Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.

SWITCHING TIME EQUIVALENT TEST CIRCUITS

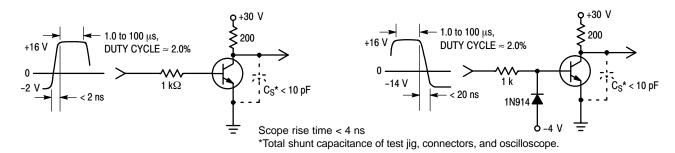


Figure 1. Turn-On Time

Figure 2. Turn-Off Time

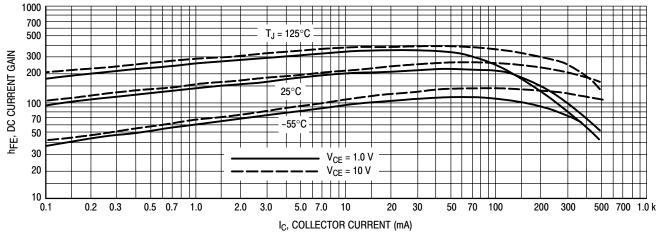


Figure 3. DC Current Gain

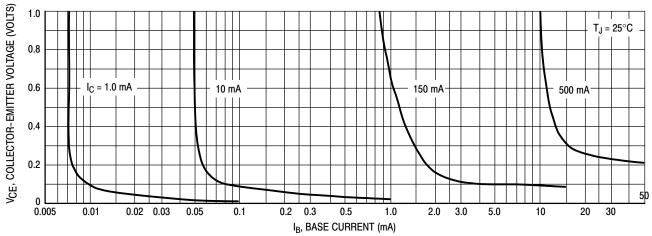


Figure 4. Collector Saturation Region

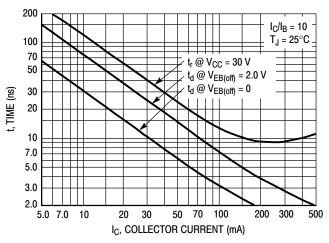


Figure 5. Turn-On Time

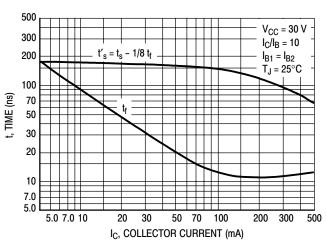


Figure 6. Turn-Off Time

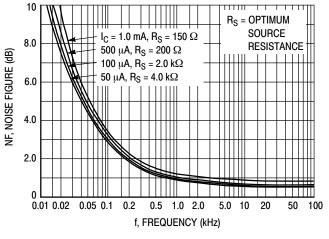


Figure 7. Frequency Effects

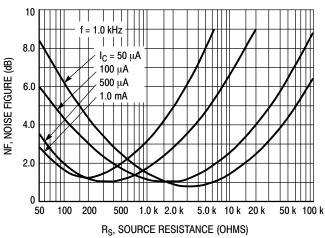


Figure 8. Source Resistance Effects

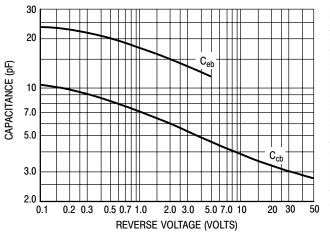


Figure 9. Capacitances

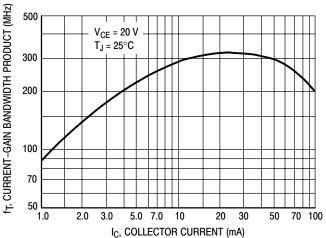


Figure 10. Current-Gain Bandwidth Product

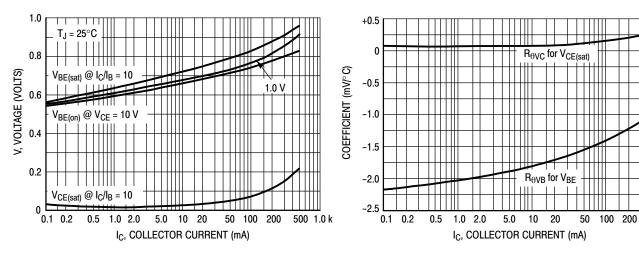


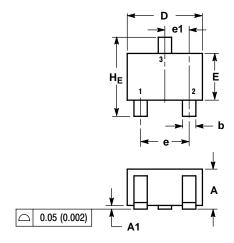
Figure 11. "On" Voltages

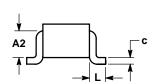
Figure 12. Temperature Coefficients

500

PACKAGE DIMENSIONS

SC-70 (SOT-323) CASE 419-04 ISSUE M





NOTES:

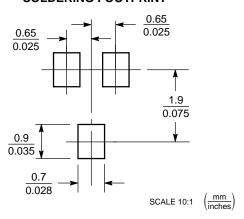
- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	MOM	MAX
Α	0.80	0.90	1.00	0.032	0.035	0.040
A1	0.00	0.05	0.10	0.000	0.002	0.004
A2	0.7 REF			0.028 REF		
b	0.30	0.35	0.40	0.012	0.014	0.016
С	0.10	0.18	0.25	0.004	0.007	0.010
D	1.80	2.10	2.20	0.071	0.083	0.087
E	1.15	1.24	1.35	0.045	0.049	0.053
е	1.20	1.30	1.40	0.047	0.051	0.055
e1	0.65 BSC 0.026 BSC			;		
L	0.425 REF			0.017 REF		
HE	2.00	2.10	2.40	0.079	0.083	0.095

STYLE 3:

PIN 1. BASE 2. EMITTER 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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